

IXFH13N100

IXFH13N100 Information

www.helseooccom	Part Number Manufacturer Category Description Package		
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IXFH13N100 Specifications

Manufacturer Part Number	IXFH13N100
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	HiPerFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1000V
Current - Continuous Drain (Id) @ 25°C	12.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4.5V @ 4mA
Gate Charge (Qg) (Max) @ Vgs	155nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4000pF @ 25V
Vgs (Max)	$\pm 20\mathrm{V}$
FET Feature	-
Power Dissipation (Max)	300W (Tc)
Rds On (Max) @ Id, Vgs	900 mOhm @ 500mA, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247AD (IXFH)
Package / Case	TO-247-3
	Report errors?

IXFH13N100 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE GUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFH13N100 Payment Methods



IXFH13N100 Shipping Methods



If you have any question about IXFH13N100, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com